

Joseph A. Powers, Esquire

Name of Person Signing

## 06-30-2003 U.S. DEPARTMENT OF COMMERCE U.S. Patent and Trademark Office OMB No. 0651-0027 (exp. 5/31/2002) 102485875 To the Honorable Commissioner of Patents and Trademarks: Please record the attached original documents or copy thereof. 1. Name of conveying party(ies): 2. Name and address of receiving party(ies) 1) Juing-Yi Cheng Name: Taiwan Semiconductor Manufacturing Co., Ltd. 2) T. L. Lee 6-23-63 3) Chia Lin Chen Internal Address: Additional name(s) of conveying party(ies) attached? Yes V No 3. Nature of conveyance: ✓ Assignment Merger Street Address: 121 Park Avenue 3 Security Agreement Change of Name Science Based Industrial Park Other\_\_\_\_ City: Hsin-Chu State: Zip: Country: Taiwan, R.O.C. Execution Date: 06/13/2003 Additional name(s) & address(es) attached? Yes V No 4. Application number(s) or patent number(s): If this document is being filed together with a new application, the execution date of the application is:\_\_\_\_\_ A. Patent Application No.(s) 10/330,850 B. Patent No.(s) Additional numbers attached? Yes 🔽 No 5. Name and address of party to whom correspondence 6. Total number of applications and patents involved: concerning document should be mailed: 7. Total fee (37 CFR 3.41).....\$ 40.00 Name: William H. Murray, Esquire ✓ Enclosed Internal Address: Duane Morris LLP Authorized to be charged to deposit account SZEWDIE1-00000105-10330850-40.00 OP 3 FC:802 8. Deposit account number: Street Address: One Liberty Place City: Philadelphia State: PA Zip: 19103 DO NOT USE THIS SPACE 9. Signature.

Mail documents to be recorded with required cover sheet information to:

Commissioner of Patents & Trademarks, Box Assignments

Washington, D.C. 20231

Total number of pages including cover sheet, attachments, and documents: 2

06/20/2003

Date

Docket No. N1085-00003 [TSMC 2002-0237]

## ASSIGNMENT AND AGREEMENT

For value received, we, Juing-Yi Cheng, T.L. Lee and Chia Lin Chen, hereby sell, assign and transfer to Taiwan Semiconductor Manufacturing Co., Ltd., with its principal place of business located at 121 Park Avenue 3, Science-Based Industrial Park. Hsin-Chu Taiwan, R.O.C., and its successors, assigns and legal representatives, the entire right, title and interest, for the United States of America, in and to certain inventions related to METHOD OF FORMING NITROGEN ENRICHED GATE DIELECTRIC WITH LOW EFFECTIVE OXIDE THICKNESS described in an application for Letters Patent of the United States Serial No. 10/330,850 filed December 27, 2002, and all the rights and privileges in said applications and under any and all Letters Patent and any divisions, continuations, continuations-in-part, reexamination certificates, reissues, and extensions thereof that may be granted in the United States for said inventions; and we also concurrently hereby sell, assign and transfer to Taiwan Semiconductor Manufacturing Co., Ltd. the entire right, title and interest in and to said inventions for all countries foreign to the United States, including all rights of priority arising from the application aforesaid, and all the rights and privileges under any and all forms of protection, including Letters Patent, that may be granted in said countries foreign to the United States for said inventions.

We authorize Taiwan Semiconductor Manufacturing Co., Ltd. to make application for such protection in its own name and maintain such protection in any and all countries foreign to the United States, and to invoke and claim for any application for patent or other form of protection for said inventions, without further authorization from us, any and all benefits, including the right of priority provided by any and all treaties, conventions, or agreements.

We hereby consent that a copy of this assignment shall be deemed a full legal and formal equivalent of any document which may be required in any country in proof of the right of Taiwan Semiconductor Manufacturing Co., Ltd. to apply for patent or other form of protection for said inventions and to claim the aforesaid benefit of the right of priority.

We request that any and all patents for said inventions be issued to Taiwan Semiconductor Manufacturing Co., Ltd. in the United States and in all countries foreign to the United States, or to such nominees as Taiwan Semiconductor Manufacturing Co., Ltd. may designate.

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Docket No. N1085-00003 [TSMC 2002-0237]

We agree that, when requested, we shall, without charge to Taiwan Semiconductor Manufacturing Co., Ltd. but at its expense, sign all papers, and do all acts which may be necessary, desirable or convenient in connection with said applications, patents, or other forms of protection.

Dated: 06/13/2003

Juing- (i theng

Residence: VNo, 256, Chi Nan Rd. I, Chi-Shan Town, Kaoshing County, R.D. C.

Dated: 13 63

T.L. Lee

Residence: 47, No 74, Lane 250, Win-Ling Rd., Hsin-chu, Taiwan.

Dated: 06/13 '03

Residence: No. 8, Alkey 33, Lane 152, See 2, Jungshing Rd., Juday Jen, Hanche, Tainen

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